

New Jersey Semi-Conductor Products, Inc.

20 STERN AVE.
SPRINGFIELD, NEW JERSEY 07081
U.S.A.

TELEPHONE: (201) 376-2922
(212) 227-6005
FAX: (201) 376-8960

1N3712-21

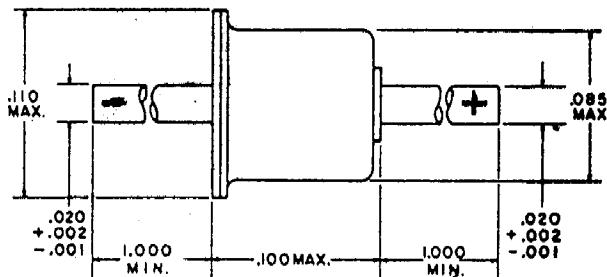
Germanium Diodes

1N3712 1N3714 1N3716 1N3718 1N3720
1N3713 1N3715 1N3717 1N3719 1N3721

Forward Current*	5	10	.25	50	100	ma
Reverse Current*	10	20	50	50	100	ma
Storage Temperature	← → -55 to +100 °C					
Lead Temperature $K_0'' \pm K_2''$ from case for 10 seconds	← → 200 °C					

*Derate maximum currents 1% per °C ambient temperature above 25°C.

AXIAL DIODE OUTLINE



ALL DIMENSIONS IN INCHES.
DIMENSIONS ARE REFERENCE UNLESS TOLERANCED.

electrical characteristics:

1N3712 1N3713 1N3714 1N3715

STATIC CHARACTERISTICS		Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.
Peak Point Current	I _P	0.9	1.0	1.1	0.975	1.000	1.025	2.0	2.2	2.4	2.15	2.20	2.25
Valley Point Current	I _V		0.12	0.18	.075	.095	.140		0.29	0.48	.165	.210	.310
Peak Point Voltage	V _P		65	58	65	72		65		58	65	72	
Valley Point Voltage	V _V		350		315	355	395		350		315	355	395
Reverse Voltage (I _R = I _P typ.)	V _R			40		20	40			40		20	40
Forward Voltage (I _F = I _P typ.)	V _{FR}		500		475	510	535		500		475	510	535
(I _F = .25 I _P typ.)	V _{FX} *				410	450				410	450		

DYNAMIC CHARACTERISTICS

Total Series Inductance	L _S	0.5		0.5		0.5		0.5		0.5		0.5	
Total Series Resistance	R _S	1.5	4.0		1.7	4.0		1.0	3.0		1.1	3.0	
Valley Point Terminal Capacitance	C	5	10		3.5	5.0		10	25		7.0	10.0	
Max. Negative Terminal Conductance	-G	8		7.5	8.5	9.5		18		16	19	22	
Resistive Cutoff Frequency	f _{rc}	2.3			3.2			2.2			3.0		
Self-Resonant Frequency	f _{sr}	3.2			3.8			2.2			2.7		
Frequency of Oscillation	F _{osc} **	3.2			3.8			2.2			2.7		
Rise Time	t _r ***				1.7					1.6			

*V_{FX} is defined as the value of forward voltage at a forward current of one quarter the typical peak current.

**The frequency of oscillation (under short circuit conditions) for steady state large signal sinusoidal oscillation is given by equation (3) which is the maximum frequency attainable without capacitance compensation.



Quality Semi-Conductors